A New Concentration Detection System for SF₆/N₂ Mixture Gas in Extra/Ultra High Voltage Power Transmission Systems

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Abstract—This paper develops a new detection system, for the first time, to detect the gas concentrations of the SF_6/N_2 mixture in extra/ultra-high voltage power transmission systems. The concentrations of SF₆ and N₂ are calculated from the thermal conductivity function of the mixture gas. The main contribution of this work is that a specially-designed thermostatic chamber with adaptive temperature controller is developed to ensure constant pressure of the gas flowed through the thermal conductivity sensor. Another contribution is the combination of multiple sensors (e.g. humidity and electrochemical sensors), which enables the detector to address the penetration effects of H₂O and O₂ in the SF₆/N₂ mixture. Experimental evaluation results using the prototype demonstrated that satisfactory accuracy (±1% of the measurement error) has been achieved for the concentration detection of the SF₆/N₂ mixture under variable operation conditions. Compared with existing detection techniques, the proposed detector not only can detect the SF₆/N₂ concentration by taking the air infiltration effect into account, but also reduce the cost.

Index Terms— SF_6/N_2 , gas mixture, microfluidic thermal conductivity sensor, constant temperature control, trace O_2

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I. INTRODUCTION

wing to outstanding insulating characteristics and arc-quenching capacity, the Sulfur hexafluoride (SF₆) gas has been widely used in extra/ultra-high voltage power transmission systems [1-5]. Usually, SF₆ gas is pressurized [6] in the electrical equipment to improve its capacitance and insulation performance because the heat capacity and dielectric strength increase with the pressure increase of SF₆. However, with the increase of the gas pressure, the liquefaction temperature of SF₆ will increase accordingly. Under the pressure of 0.22 MPa (i.e., 275 kV level), its liquefaction temperature is -40°C, whereas under 0.6 MPa (i.e., 500 kV level), the liquefaction temperature increases to -25°C [7]. In cold regions, the liquefaction of the SF₆ gas will cause the decrease of the SF₆ pressure inside the electrical equipment, resulting in degradation of insulation performance [8]. In addition, SF₆ gas is very costly and sensitive to non-uniform electric field [9]. The contribution of greenhouse effect of SF₆ is 23,900 times of CO₂ [10, 11]. More importantly, SF₆ has been included in the gas list by the Kyoto Protocol (1997), whose emissions should be limited [12]. Hence, it is crucial to develop alternatives to SF₆ in electrical equipment [13, 14].

Currently, the development of environmental-friendly replacement of SF₆ is a hot topic, aiming to improve the insulation properties and reduce greenhouse effect of the gas in electrical equipment [15-18]. The mixture of SF₆/N₂ is an promising alternative to SF6 and has shown good potentials for practical applications [19, 20]. For example, when the content of SF₆ is 50% in the SF₆/N₂ mixture in uniform electric field, the electric strength of the mixed gas is almost 85% of the strength of the pure SF_6 gas [17]. In addition, the cost of SF_6/N_2 is much cheaper and the emission is much smaller than that of SF₆ while the stability and safety levels of SF₆/N₂ are much higher than that of SF₆. The liquefaction problem of SF₆ is also solved by the mixture of SF6/N2 (e.g., the liquefaction point of 60% SF6+40% N2 mixture is -42°C under 0.6 MPa). As a result, the SF₆/N₂ mixture gas is gradually replacing the SF₆ gas in extra/ultra-high voltage transmission systems [21-23]. For

example, the insulation performance of SF_6/N_2 has already been evaluated in a real world 550 kV power transmission system by the New Northeast Electric Company [22]. For another example, in more than 200 km of GIL (gas-insulated transmission line) installed by Alstom Grid, the SF_6/N_2 mixture has been considered in insulation design [13].

However, in practice H₂O and O₂ may penetrate into the SF₆/N₂ mixture during its service life, resulting in insulation performance degradation. For instance, the seal device may deteriorate after some usage time and H₂O and O₂ in the air may penetrate through the seal into the SF₆/N₂ mixture. It is crucial to detect the concentration of H₂O and O₂ in practice while an effective detection system is not developed in literature. Most of existing systems are developed for SF₆ detection [24]. Generally, there are thermal conductivity sensor based [25], Infrared sensor based [26], ultrasonic sensor based [27], and photo-acoustic sensor based [2, 28] SF₆ gas detection systems. Huang et al. [22] used the thermal conductivity sensor to detect the SF₆ concentration in electrical equipment. Wang et al. [26] combined the infrared and electrochemical SO2 sensors to detect the SF6 decomposition. Stone [27] used the ultrasonic sensor for partial discharge diagnostics in electrical equipment. Sherstov et al. [28] adopted the photo-acoustic sensor for SF₆ detection. However, to the best of our knowledge, the detection of SF₆/N₂ mixture considering the H₂O and O₂ elements has not been found yet in literature [29-31].

In order to address the aforementioned issue, this paper aims to develop a new detection system for concentration detection of SF_6/N_2 mixture considering the H_2O and O_2 penetration effect in extra/ultra-high voltage power transmission systems. The working principle and detailed hardware construction were described in this paper. Particularly, the humidity and micro-oxygen sensors were integrated into the detection system to detect the H_2O and O_2 concentration in the SF_6/N_2 mixture. A temperature control circuit and specially-designed thermal conductivity room were developed to make accurate detection results of the SF_6 and N_2 concentrations. The contribution/novelty of this work include

- the developed system is applicable and effective to detecting SF₆/N₂ mixture with H₂O and O₂ penetration effect;
- 2) for the first time, a prototype of the proposed detection system is developed.

Experimental tests under regular and extreme operating conditions were conducted to evaluate the performance of the prototype on SF_6/N_2 concentration detection.

II. THE PROPOSED DETECTION SYSTEM

A. System Design Principle

Fig. 1 depicts the overall design of the SF₆/N₂ concentration detection system, which is mainly consisted of one thermostatic chamber temperature detection and control module, one signal

detection and conditioning module, one moisture detection module, one oxygen detection and conditioning module, and one flow monitoring and conditioning module. The thermal detection module is installed in the thermal conduction chamber to ensure the consistency of the heat detection. The micro-thermal conductivity sensor TCS208F is used and its output is recorded by the signal detection and conditioning module. The moisture detection module adopts DMT242J sensor to detect H₂O in the gas mixture and the oxygen detection and conditioning module measures the concentration of trace O₂. The flow monitoring and conditioning module adopts the mass flow meter to measure the gas flow rate.

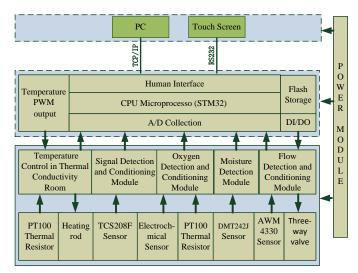


Fig. 1. The overall design of the SF₆/N₂ concentration detection system.

B. Detection Principle of SF₆/N₂ Mixture

Based on MEMS structure, the microfluidic thermal conductivity sensor (TCS208F) integrates metal thin-film thermosensitive elements, and in each element there are four resistors (R_{m1} , R_{m2} , R_{t1} and R_{t2}). R_{m1} and R_{m2} are used to heat the film and measure the film temperature. R_{t1} and R_{t2} are used to detect the ambient temperature and perform temperature compensation. Neglecting the effect of thermal convection and thermal radiation in the TCS208F sensor, the operation power of the film can be expressed as

$$P = I_{\rm m}^2 \cdot R_{\rm m} \cdot (1 + \alpha \cdot T_{\rm m})$$

= $I_{\rm m}^2 \cdot R_{\rm m} \cdot [1 + \alpha \cdot (T_{\rm m} - T + T)]$ (1)

where I_m is the sensor current, R_m (= $R_{m1} + R_{m2}$) is the film resistor, α is the temperature coefficient, T_m is the operation temperature, and T is the initial ambient temperature.

Because the sensor heat is completely absorbed by the gas, the thermal equilibrium model in Eq. (1) can be simplified as

$$P = Q_1 = \lambda \cdot S \cdot (T_m - T) \tag{2}$$

Where λ is the gas thermal conductivity and S is the contact area between the film resistor and gas. The temperature difference ΔT after thermal equilibrium is

$$\Delta T = T_{\rm m} - T = (1 + \alpha T) \left(\frac{S \cdot \lambda}{I_{\rm m}^2 R_{\rm m}} - \alpha \right)^{-1}.$$
 (3)

In order to ensure that the microfluidic thermal conductivity sensor works stably, a temperature control circuit is designed for the thermal conductivity sensor (see Fig. 2). In Fig. 2, the operational amplifier TLC2652 is used to amplify the micro signals. R_{t1} is controlled by the microcontroller to keep the temperature as a constant.

$$R_{t1} = \frac{R_1}{R_2} \cdot (R_{m1} + R_{m2}) \cdot (1 + \alpha \Delta T)$$

$$= \frac{R_1 \cdot R_m}{R_2} \cdot (1 + \alpha \cdot \Delta T)$$
(4)

where R_1 and R_2 are the resistors of the control circuit. Thus, the thermal conductivity of the mixture gas can be calculated by

$$\lambda = \frac{\alpha \cdot U_0^2}{S} \cdot \frac{R_{\text{m}} \cdot R_{\text{tl}}}{R_{\text{tl}} R_2^2 - R_{\text{m}} \cdot R_1 \cdot R_2} \,. \tag{5}$$

where U_0 is the sensor voltage. Eq. (5) is the thermal conductivity of SF₆, N₂ and O₂ mixture.

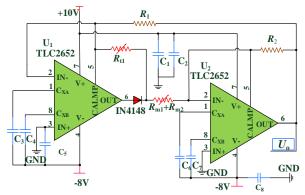


Fig. 2. The temperature control circuit of the thermal conductivity sensor.

When the system reaches the thermal equilibrium, R_m and R_{11} can be considered as constant values. As a result, a linear relationship can be learnt between U_0 and λ from Eq. (5). Let us assume that the O_2/H_2O content infiltrated into the SF_6/N_2 mixtures meets the requirements of IEC60480-2004 [32]. So the chemical reactions in equilibrium condition can be expressed as follows:

$$e + SF_6 \rightarrow SF_n + (6-n)F + e, n \leq 5$$

$$SF_2 + O_2 \rightarrow SO_2F_2$$

$$e + O_2 \rightarrow O + O + e$$

$$SF_5 + O \rightarrow SOF_4 + F$$

Figure 3 depicts the equivalent diagram of the thermal conductivity sensor at its thermal equilibrium condition. It is used as a signal conditioning device to control the temperature of the gas.

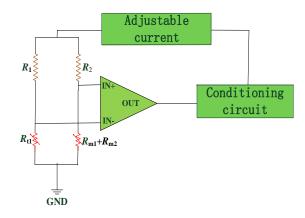


Fig. 3. The equivalent diagram of temperature control circuit in Fig. 2.

In Fig. 3, the Wheatstone bridge can be fall into balance condition through adjusting the resistances R_1 and R_2 after the passing of SF_6/N_2 mixture. The current determines the working temperature of the sensor at this moment. When the measured gas is passed through the sensor, the coefficient of thermal conductance λ will increase, resulting in the decrease of the sensor temperature and the measured resistance R_m . As a result, the bridge is out of balance, and the unbalanced voltage is amplified and sent to the regulation circuit, where the output of the current source is adjusted so that the current is increased with the decrease of the sensor temperature. By doing so, no matter how the thermal conductivity λ changes, the sensor temperature can keep as a constant to prevent inaccurate measurement or sensor damage due to overheating.

In order to determine the thermal conductivity of SF_6/N_2 , it needs to know the thermal conductivity of O_2 . In the gas mixture of SF_6 , N_2 , H_2O and O_2 , due to the absence of the chemical reaction between the components, the thermal conductivity is approximated by the arithmetic mean of the thermal conductivity in Eq. (6).

$$\lambda = \lambda_1 C_1 + \lambda_2 C_2 + \lambda_3 C_3 + \lambda_4 C_4 \tag{6}$$

Where λ denotes the thermal conductivity of the gas mixture, λ_i (i = 1, 2, 3, 4) respectively denotes the thermal conductivity of SF₆, N₂ and O₂, and C_i (i = 1, 2, 3, 4) is the volume percentage of λ_i . The sum of volume percentage parameters satisfies

$$C_1 + C_2 + C_3 + C_4 = 1 \tag{7}$$

From Eqs. (6) and (7) it can be seen that the concentrations of SF_6 and N_2 can be obtained as long as the H_2O and O_2 is detected.

C. Detection of the Oxygen Concentration

The micro-oxygen sensor is based on a lead-oxygen battery, including a lead anode, a gold cathode, and an alkaline electrolyte. Oxygen molecules enter into the electrochemical cell through a non-porous fluorine resin membrane and are reduced at the gold electrode. Without considering the temperature effect, the current generated by the Oxygen sensor is proportional to the oxygen concentration in the mixture gas [17]. When the membrane permeability is very low, the gas pressure is constant. This is because in the front end of the heat conduction chamber (see Section III) there is a long spiral tube buffer and a constant pressure device. The back-end of the heat conduction chamber is connected with the atmospheric pressure recovery device. If the external load resistance is small enough, the sensor output current can be expressed as

$$i_d = k \cdot C_{p3} \tag{8}$$

where, i_d is the sensor output current, k is the current concentration coefficient associated with the sensor structure and temperature, and C_{p3} is the measured oxygen concentration.

The output signal (i.e., 0-5V voltage) is converted by the conditioning circuit in Fig. 4. The input of the conditioning circuit is the output signal of the oxygen sensor, which is conversed to the corresponding oxygen concentration by CPU.

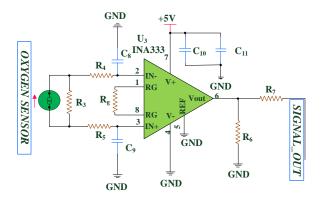


Fig. 4. Oxygen sensor conditioning circuit.

D. Detection of Moisture Concentration

The DMT242J moisture sensor and PT-100 thermal resistor are combined to measure the moisture in the mixture gas (see Fig. 1). DMT242J is usually used for reliable dew-point measurement in dry processes (such as industrial dryer applications). It mainly consists of a high polymer humicap and

a thermistor. Its capacitance value is proportional to relative humidity (RH) of the gas. PT-100 measures the temperature (T) of the gas. According to the Goff-Gratch and Wexler correction formulae, the Saturation Vapour Pressure P_{ws} at current temperature T can be obtained. So the vapour pressure P_{w} in the gas can be calculated by

$$P_{w} = RH \cdot P_{ws} \tag{9}$$

Then the absolute moisture amount can be calculated from P_w using the specific parameters of DMT242.

E. A Calculation Example

In order to illustrate the process of the concentration detection of the proposed system, an example is carried out. The calculation process can be expressed as the following five steps.

Step 1: Calculate the thermal conductivity \square of the gas mixture using Eq. (5)

Step 2: Measure the O_2 and H_2O concentration using the electrochemical and moisture sensors to obtain C_3 and C_4 in Eq. (6) at the current temperature T

Step 3: Find λ_i (i = 1, 2, 3, 4) at temperature T

Step 4: Solve Eqs. (6) and (7) to get the results of C_1 and C_2 Step 5: The concentrations of SF₆ and N₂ are respectively C_1 and C_2

For example, given the temperature of 65 °C, the thermal conductivity of SF₆, N₂, H₂O and O₂ are $\lambda_1 = 4.6$ W/mK, $\lambda_2 = 6.9$ W/mK, $\lambda_3 = 4$ W/mK and $\lambda_4 = 7$ W/mK. The thermal conductivity λ of the gas mixture can be calculated by Eq. (5), i.e., $\lambda = 5.5$ W/mK. Then we measure the concentrations of H₂O and O₂ by the mixture and electrochemical sensors as $C_3 = 0.1\%$ and $C_4 = 0.6\%$. Substituting these values into Eqs. (6) and (7) we can derive

$$\begin{cases} 4.6 \times C_1 + 6.9C_2 + 4 \times 0.1\% + 7 \times 0.6\% = 5.5 \\ C_1 + C_2 + 0.1\% + 0.6\% = 1 \end{cases}$$
(10)

By solving Eq. (10) it yields $C_1 = 60.8\%$ and $C_2 = 38.5\%$, i.e., the concentrations of SF₆ and N₂ are respectively 60.8% and 38.5%.

III. PROTOTYPE OF THE PROPOSED DETECTION SYSTEM

A. Design of Thermal Conductivity Room

In order to ensure constant pressure of the gas flowed through the thermal conductivity sensor, a specially-designed thermostatic chamber is developed. The mechanical structure of the thermostatic chamber is shown in Fig. 5, where the inlet spiral pipeline functions as a buffer to stabilize the pressure of the gas flow. Then the gas is preheated by a helical heating rod, in which the temperature is controlled by the temperature conditioning circuit (see Fig. 2) to keep as a constant value for the chamber. Thanks to the buffer effect and heating function of

the chamber, smooth gas pressure and constant temperature can be achieved to reduce/eliminate the measure error of the thermal conductivity sensor.

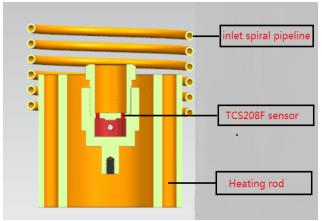


Fig. 5. Mechanical structure of the thermostatic chamber.

Here a simulation analysis was conducted to determine the optimum operating temperature of the thermal conductivity sensor. A simplified model of TCS208F microfluidic thermal conductivity sensor was established by FLUENT software. The flow-solid coupling field of the sensor model was simulated in a 20 mL/min air flow-field. The analysis result is shown in Fig. 6. From the sensor temperature diagram in the figure it can be seen that, the central temperature of the sensor reaches to $336\sim343$ K (i.e., $63\sim70^{\circ}$ C). Hence, it is generally recommended that the difference temperature ΔT between the sensor operation temperature and ambient temperature is within 50° C, and the working temperature of the thermostatic chamber is within 75° C.

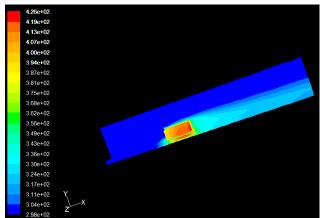


Fig. 6. Cloud picture around the TCS208F ambient temperature.

B. Prototype of the Proposed Detection System

The prototype of the proposed SF_6/N_2 concentration detector is shown in Fig. 7. When the temperature of the thermostatic chamber is stabilized at the setting value, the gas mixture enters into the thermostatic chamber. The TCS208F microfluidic

thermal conductivity sensor then detects the SF_6/N_2 concentration. The detection result will be displayed in the screen and saved in the signal module.



Fig. 7. The prototype of the proposed SF6/N2 concentration detector.

IV. RESULTS AND DISCUSSION

The detector prototype (see Fig. 7) was used to detect the mixture of SF₆, N₂, H₂O and O₂ in the experimental test (see Fig. 8). According to CIGRE [33, 34], these four gases were diluted by a standard gas dilution device with a concentration of 32.19% (SF₆), 67.2% (N₂), 0.01% (H₂O) and 0.6% (O₂). Ten samples of the mixed gas were prepared and passed into the detector in the experiments. The temperature of the chamber was 22°C±3°C. The concentration of each gas element in each sample was repeatedly measured for 8 times under the stable operation condition of the detector, and the mean value of the measurements was taken as the final measurement for each sample. Fig. 9 manifests the detection results for the concentrations of the mixture gas using one sample. As can be seen in Fig. 9, the measured concentrations of the four gas elements were well consistent with the true values in the mixture. The mean square errors of the detection results in Fig. 9 were less than 0.05% for each element. Hence, the concentration detection accuracy of the prototype meets industrial criterion.



Fig. 8. The experimental tests using the proposed SF6/N2 concentration detection prototype.

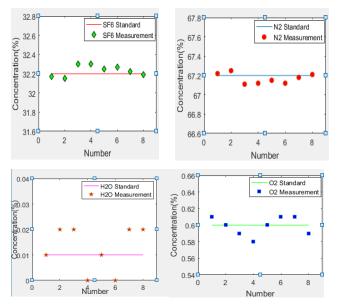


Fig. 9. The concentration detection results: (upper left) SF6, (upper right) N_2 , (lower left) H_2O , and (lower right) O_2 .

Furthermore, the detection performance of the prototype was evaluated under extreme temperature conditions of the chamber, that is, high temperature (40°C±3°C) and low temperature (-10°C±3°C) conditions. Ten samples were prepared for each extreme condition. The repeatability error C_r of the detection results was calculated by Eq. (11).

$$C_{\rm r} = \frac{1}{\overline{N}} \left(\sum_{i=1}^{8} (N_i - \overline{N}) \right)^{\frac{1}{2}} \times 100\% \ . \tag{11}$$

where, N_i (i = 1, 2, ..., 8) is the *i*th measurement of each element in one sample, and \overline{N} is the mean value of the

concentration of each gas for this sample. The concentration detection errors of the four elements in the gas mixture are shown in Fig. 10.

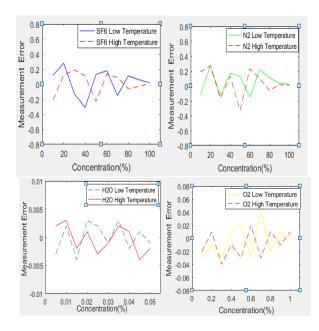


Fig. 10. The detection results under extreme temperature conditions: (upper left) SF_6 , (upper right) N_2 , (lower left) H_2O , and (lower right) O_2 .

As can be seen in Fig. 10, the detection errors of SF_6 , N_2 , H_2O and O_2 for one sample were 0.41%, 0.43%, 0.002% and 0.04%, respectively. The averaging repeated detection errors for all 10 samples were $\pm 0.21\%$, $\pm 0.09\%$, $\pm 1.4\%$ and $\pm 1.3\%$ for the four gas elements, respectively. According to the International ISO Standard 14040 [35], IEC60480-2004 [32] and National Standard of China, the maximum allowable error of the detector for SF_6 , N_2 , H_2O and O_2 are respectively $\pm 0.5\%$, $\pm 0.5\%$, $\pm 0.05\%$ and $\pm 0.05\%$. The maximum allowable repeatability errors are 1%, 1%, 2% and 2%. As a result, the detection accuracy and reliability of the prototype under extreme high and low temperature conditions meet the industrial requirements.

In this work the thermal conductivity sensor is adopted in the detector. This is because the thermal conductivity sensor based system is much cheaper than that of the infrared sensor or ultrasonic sensor or photo-acoustic sensor based systems. For instance, the price of thermal conductivity sensor based system is only 1/5 of the infrared sensor system. In addition, the infrared sensors are often subject to temperature changes while the propose system has been proven to be robust to temperature. Furthermore, current international standards [32-34] require that the gas concentration is expressed as a mass concentration unit. Thanks to the specially-designed thermostatic chamber with temperature control unit, the measured volume concentration (ppm) of the proposed detection system can be

easily converted into mass concentration (e.g., mg/m³) while some other sensor measurements (e.g., infrared sensor and ultrasonic sensor) need to add pressure and temperature modules for the conversion, which may increase the cost and complexity of the detection system further. As a result, the thermal conductivity sensor is more suitable for the proposed detection system than other sensors in practical applications.

V. CONCLUSION

To address the industrial demand on accurate and reliable concentration detection of SF₆/N₂ mixture in extra/ultra-high voltage power transmission systems, this paper introduces a new system for the mixture concentration detection. The effect of H₂O and O₂ infiltration on the concentration of the mixture is solved by this new detector. The prototype of the proposed concentration detector for SF₆/N₂ mixture has been manufactured. The detection results of the prototype demonstrated that the measurement errors of SF₆ and N₂ were within $\pm 0.05\%$, and their repeatability error was less than 1.0%. The measurement errors of H_2O and O_2 were less than 0.04%, and their repeatability errors were less than 2%. According to the International ISO 14040 and IEC60480-2004 standards, these detection errors fulfil the industrial requirements. The proposed detector was also suitable and effective for SF₆/N₂ detection under extremely temperature conditions. As a result, the proposed detector is applicable to practical applications.

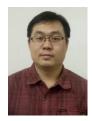
The reliability issue of the proposed detection system is worth investigating. In this work we only have tested its performance under (40°C±3°C) and (-10°C±3°C). Because a thermostatic chamber is designed to stabilize the gas pressure and a temperature control circuit is used to obtain suitable operating temperature of the sensors, the detection system is expected to be safe under the tested extreme conditions in this work. In future we will comprehensively investigate the reliability issue of the proposed detection system using finite element analysis and experimental evaluation to discuss the influence factors to the system reliability under more severe operating conditions. In addition, future work will also compare the concentration detection performance of different sensors (e.g., infrared sensor or ultrasonic sensor or photo-acoustic sensor) using the sensor-array technique in the designed thermostatic chamber.

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